# ESP32-WROOM-32E ESP32-WROOM-32UE

# **Datasheet**

2.4 GHz Wi-Fi + Bluetooth® + Bluetooth LE module
Built around ESP32 series of SoCs, Xtensa® dual-core 32-bit LX6 microprocessor
4/8/16 MB flash available
26 GPIOs, rich set of peripherals
On-board PCB antenna or external antenna connector



ESP32-WROOM-32E



ESP32-WROOM-32UE



# 1 Module Overview

#### Note:

Check the link or the QR code to make sure that you use the latest version of this document: https://espressif.com/documentation/esp32-wroom-32e\_esp32-wroom-32ue\_datasheet\_en.pdf



### 1.1 Features

#### **CPU and On-Chip Memory**

- ESP32-D0WD-V3 or ESP32-D0WDR2-V3 embedded, Xtensa dual-core 32-bit LX6 microprocessor, up to 240 MHz
- 448 KB ROM
- 520 KB SRAM
- 16 KB SRAM in RTC
- ESP32-D0WDR2-V3 also provides 2 MB PSRAM

#### Wi-Fi

- 802.11b/g/n
- Bit rate: 802.11n up to 150 Mbps
- A-MPDU and A-MSDU aggregation
- 0.4  $\mu$ s guard interval support
- Center frequency range of operating channel: 2412 ~ 2484 MHz

#### Bluetooth

- Bluetooth V4.2 BR/EDR and Bluetooth LE specification
- Class-1, class-2 and class-3 transmitter
- AFH
- CVSD and SBC

#### Peripherals

 SD card, UART, SPI, SDIO, I2C, LED PWM, Motor PWM, I2S, IR, pulse counter, GPIO, capacitive touch sensor, ADC, DAC, TWAI<sup>®</sup> (compatible with ISO 11898-1, i.e. CAN Specification 2.0)

## **Integrated Components on Module**

- 40 MHz crystal oscillator
- 4/8/16 MB SPI flash

#### **Antenna Options**

- ESP32-WROOM-32E: On-board PCB antenna
- ESP32-WROOM-32UE: external antenna via a connector

#### **Operating Conditions**

- Operating voltage/Power supply: 3.0 ~ 3.6 V
- Operating ambient temperature:
  - 85 °C version: -40 ~ 85 °C
  - 105 °C version: -40 ~ 105 °C. Note that only the modules embedded with a 4/8 MB flash support this version.

#### Certification

- Bluetooth certification: BQB
- RF certification: See certificates for <u>ESP32-WROOM-32E</u> and <u>ESP32-WROOM-32UE</u>
- Green certification: REACH/RoHS

# **Reliability Test**

• HTOL/HTSL/uHAST/TCT/ESD

# 1.2 Description

ESP32-WROOM-32E and ESP32-WROOM-32UE are two powerful, generic Wi-Fi + Bluetooth + Bluetooth LE MCU modules that target a wide variety of applications, ranging from low-power sensor networks to the most demanding tasks, such as voice encoding, music streaming and MP3 decoding.

ESP32-WROOM-32E comes with a PCB antenna, and ESP32-WROOM-32UE with a connector for an external antenna. The information in this datasheet is applicable to both modules.

The Series Comparison for the two modules is as follows:

Table 1: ESP32-WROOM-32E Series Comparison<sup>1</sup>

Ordering Code	Flash	PSRAM	Ambient Temp. <sup>2</sup> (°C)	Size <sup>3</sup> (mm)
ESP32-WROOM-32E-N4	4 MB (Quad SPI)	_	<b>−</b> 40 <b>~</b> 85	
ESP32-WROOM-32E-N8	8 MB (Quad SPI)	_	<b>−</b> 40 <b>~</b> 85	
ESP32-WROOM-32E-N16	16 MB (Quad SPI)	_	<b>−</b> 40 <b>~</b> 85	
ESP32-WROOM-32E-H4	4 MB (Quad SPI)	_	<b>−</b> 40 <b>~</b> 105	18.0 × 25.5 × 3.1
ESP32-WROOM-32E-H8	8 MB (Quad SPI)	_	<b>−</b> 40 <b>~</b> 105	10.0 x 20.0 x 3.1
ESP32-WROOM-32E-N4R2	4 MB (Quad SPI)	2 MB (Quad SPI) <sup>4</sup>	<b>−</b> 40 <b>~</b> 85	
ESP32-WROOM-32E-N8R2	8 MB (Quad SPI)	2 MB (Quad SPI) <sup>4</sup>	<b>−</b> 40 <b>~</b> 85	
ESP32-WROOM-32E-N16R2	16 MB (Quad SPI)	2 MB (Quad SPI) <sup>4</sup>	<b>−</b> 40 <b>~</b> 85	

<sup>&</sup>lt;sup>1</sup> This table shares the same notes presented in the table 2 below.

Table 2: ESP32-WROOM-32UE Series Comparison

Ordering Code	Flash	PSRAM	Ambient Temp. <sup>2</sup>	Size <sup>3</sup>
Ordering Code	гіазіі	FORAIVI	(°C)	(mm)
ESP32-WROOM-32UE-N4	4 MB (Quad SPI)	_	<b>−</b> 40 <b>~</b> 85	
ESP32-WROOM-32UE-N8	8 MB (Quad SPI)	_	<b>−</b> 40 <b>~</b> 85	
ESP32-WROOM-32UE-N16	16 MB (Quad SPI)	_	<b>−</b> 40 <b>~</b> 85	
ESP32-WROOM-32UE-H4	4 MB (Quad SPI)	_	<b>−</b> 40 <b>~</b> 105	18.0 × 19.2 × 3.2
ESP32-WROOM-32UE-H8	8 MB (Quad SPI)	_	<b>−</b> 40 <b>~</b> 105	10.0 x 19.2 x 3.2
ESP32-WROOM-32UE-N4R2	4 MB (Quad SPI)	2 MB (Quad SPI) <sup>4</sup>	<b>−</b> 40 <b>~</b> 85	
ESP32-WROOM-32UE-N8R2	8 MB (Quad SPI)	2 MB (Quad SPI) <sup>4</sup>	<b>−</b> 40 <b>~</b> 85	
ESP32-WROOM-32UE-N16R2	16 MB (Quad SPI)	2 MB (Quad SPI) <sup>4</sup>	<b>−</b> 40 <b>~</b> 85	

<sup>&</sup>lt;sup>2</sup> Ambient temperature specifies the recommended temperature range of the environment immediately outside the Espressif module.

At the core of the module is the ESP32-D0WD-V3 chip or ESP32-D0WDR2-V3 chip\*. The chip embedded is designed to be scalable and adaptive. There are two CPU cores that can be individually controlled, and the CPU clock frequency is adjustable from 80 MHz to 240 MHz. The chip also has a low-power coprocessor that can be used instead of the CPU to save power while performing tasks that do not require much computing power, such as monitoring of peripherals. ESP32 integrates a rich set of peripherals, ranging from capacitive touch sensors,

<sup>&</sup>lt;sup>3</sup> For details, refer to Section 7.1 *Physical Dimensions*.

<sup>&</sup>lt;sup>4</sup> This module uses PSRAM integrated in the chip's package.

SD card interface, Ethernet, high-speed SPI, UART, I2S, and I2C.

#### Note:

\* For details on the part numbers of the ESP32 family of chips, please refer to the document ESP32 Series Datasheet.

The integration of Bluetooth, Bluetooth LE and Wi-Fi ensures that a wide range of applications can be targeted, and that the module is all-around: using Wi-Fi allows a large physical range and direct connection to the Internet through a Wi-Fi router, while using Bluetooth allows the user to conveniently connect to the phone or broadcast low energy beacons for its detection. The sleep current of the ESP32 chip is less than 5  $\mu$ A, making it suitable for battery powered and wearable electronics applications. The module supports a data rate of up to 150 Mbps, and 20 dBm output power at the antenna to ensure the widest physical range. As such the module does offer industry-leading specifications and the best performance for electronic integration, range, power consumption, and connectivity.

The operating system chosen for ESP32 is freeRTOS with LwIP; TLS 1.2 with hardware acceleration is built in as well. Secure (encrypted) over the air (OTA) upgrade is also supported, so that users can upgrade their products even after their release, at minimum cost and effort.

# 1.3 Applications

- Generic Low-power IoT Sensor Hub
- Generic Low-power IoT Data Loggers
- Cameras for Video Streaming
- Over-the-top (OTT) Devices
- Speech Recognition
- Image Recognition
- Mesh Network
- Home Automation

- Smart Building
- Industrial Automation
- Smart Agriculture
- Audio Applications
- Health Care Applications
- Wi-Fi-enabled Toys
- Wearable Electronics
- Retail & Catering Applications

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# 2 Block Diagram

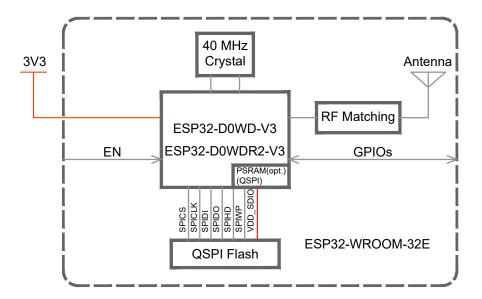


Figure 1: ESP32-WROOM-32E Block Diagram

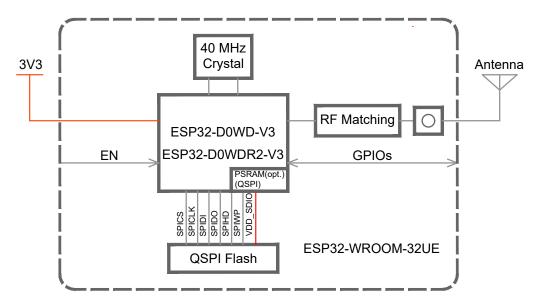


Figure 2: ESP32-WROOM-32UE Block Diagram

# **Pin Definitions**

# 3.1 Pin Layout

The pin layout of ESP32-WROOM-32UE is the same as that of ESP32-WROOM-32E, except that ESP32-WROOM-32UE has no keepout zone.

The pin diagram below shows the approximate location of pins on the module. For the actual diagram drawn to scale, please refer to Figure 7.1 Physical Dimensions.

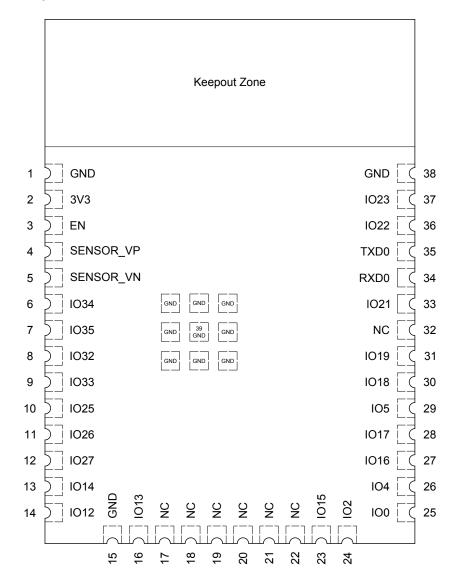


Figure 3: Pin Layout (Top View)

#### **Pin Description** 3.2

The module has 38 pins. See pin definitions in Table 3.

For peripheral pin configurations, please refer to ESP32 Series Datasheet.

Table 3: Pin Definitions

GND	Name	No.	Type <sup>1</sup>	Function
High: On; enables the chip	GND	1	Р	Ground
EN 3 I Low: Off; the chip shuts down Note: Do not leave the pin floating.  SENSOR_VP 4 I GPIO36, ADC1_CH0, RTC_GPIO0  SENSOR_VN 5 I GPIO39, ADC1_CH3, RTC_GPIO3  IO34 6 I GPIO34, ADC1_CH6, RTC_GPIO4  IO35 7 I GPIO35, ADC1_CH7, RTC_GPIO5  IO32 8 I/O GPIO32, XTAL_32K_P (32.768 kHz crystal oscillator input), ADC1_CH4, TOUCH9, RTC_GPIO9  IO33 9 I/O GPIO32, XTAL_32K_N (32.768 kHz crystal oscillator output), ADC1_CH4, TOUCH9, RTC_GPIO9  IO25 10 I/O GPIO25, DAC_1, ADC2_CH8, RTC_GPIO6, EMAC_RXD0  IO26 11 I/O GPIO26, DAC_2, ADC2_CH9, RTC_GPIO7, EMAC_RXD1  IO27 12 I/O GPIO27, ADC2_CH6, TOUCH6, RTC_GPIO17, EMAC_RX_DV  IO14 13 I/O GPIO14, ADC2_CH6, TOUCH6, RTC_GPIO16, MTMS, HSPICLK, HS2_CLK, SD_CLK, EMAC_TXD2  GPIO14, ADC2_CH5, TOUCH5, RTC_GPIO15, MTDI, HSPIQ, HS2_DATA2, SD_DATA2, EMAC_TXD3  GRND 15 P Ground  IO13 16 I/O GPIO13, ADC2_CH4, TOUCH4, RTC_GPIO14, MTCK, HSPID, HS2_DATA3, SD_DATA3, EMAC_RX_ER  NC 17 - See note 2  NC 19 - See note 2  NC 20 - See note 2  NC 21 - See note 2  NC 21 - See note 2  NC 22 - See note 2  NC 22 - See note 2  IO15 23 I/O GPIO15, ADC2_CH3, TOUCH3, MTDO, HSPICSO, RTC_GPIO13, HS2_CMD, SD_CMD, EMAC_RXD3  GPIO2 ADC2_CH3, TOUCH3, MTDO, HSPICSO, RTC_GPIO13, HS2_CMD, SD_CMD, EMAC_RXD3  GPIO2 ADC2_CH3, TOUCH3, MTDO, HSPICSO, RTC_GPIO13, HS2_CMD, SD_CMD, EMAC_RXD3  GPIO2 ADC2_CH3, TOUCH3, MTDO, HSPICSO, RTC_GPIO13, HS2_CMD, SD_CMD, EMAC_RXD3  GPIO2 ADC2_CH3, TOUCH3, RTC_GPIO12 HSPIWP HS2_DATA0	3V3	2	Р	Power supply
Note: Do not leave the pin floating.				High: On; enables the chip
SENSOR_VP	EN	3	I	Low: Off; the chip shuts down
SENSOR_VN   5				Note: Do not leave the pin floating.
IO34	SENSOR_VP	4	I	GPIO36, ADC1_CH0, RTC_GPIO0
IO35	SENSOR_VN	5	ı	GPIO39, ADC1_CH3, RTC_GPIO3
IO32	IO34	6	ı	GPIO34, ADC1_CH6, RTC_GPIO4
IO32	IO35	7	ı	GPIO35, ADC1_CH7, RTC_GPIO5
IO33	IO32	8	I/O	· · ·
1025	IO33	9	I/O	
IO26	IO25	10	I/O	
IO14	IO26	11	I/O	
IO14	IO27	12	I/O	GPIO27, ADC2 CH7, TOUCH7, RTC GPIO17, EMAC RX DV
HS2_CLK, SD_CLK, EMAC_TXD2				GPIO14, ADC2_CH6, TOUCH6, RTC_GPIO16, MTMS, HSPICLK,
IO12	IO14	13	1/0	HS2_CLK, SD_CLK, EMAC_TXD2
HS2_DATA2, SD_DATA2, EMAC_TXD3				
IO13	1012	14	I/O	HS2_DATA2, SD_DATA2, EMAC_TXD3
NC	GND	15	Р	Ground
HS2_DATA3, SD_DATA3, EMAC_RX_ER	1010	10	1/0	GPIO13, ADC2_CH4, TOUCH4, RTC_GPIO14, MTCK, HSPID,
NC         18         -         See note <sup>2</sup> NC         19         -         See note <sup>2</sup> NC         20         -         See note <sup>2</sup> NC         21         -         See note <sup>2</sup> NC         22         -         See note <sup>2</sup> IO15         23         I/O         GPIO15, ADC2_CH3, TOUCH3, MTDO, HSPICSO, RTC_GPIO13, HS2_CMD, SD_CMD, EMAC_RXD3           GPIO2 ADC2 CH2 TOUCH2 BTC GPIO12 HSPIWP HS2 DATAO	1013	16	1/0	HS2_DATA3, SD_DATA3, EMAC_RX_ER
NC         19         -         See note <sup>2</sup> NC         20         -         See note <sup>2</sup> NC         21         -         See note <sup>2</sup> NC         22         -         See note <sup>2</sup> IO15         23         I/O         GPIO15, ADC2_CH3, TOUCH3, MTDO, HSPICSO, RTC_GPIO13, HS2_CMD, SD_CMD, EMAC_RXD3           GPIO2 ADC2 CH2 TOUCH2 BTC GPIO12 HSPIWP HS2 DATAO	NC	17	-	See note <sup>2</sup>
NC         20         -         See note <sup>2</sup> NC         21         -         See note <sup>2</sup> NC         22         -         See note <sup>2</sup> IO15         23         I/O         GPIO15, ADC2_CH3, TOUCH3, MTDO, HSPICSO, RTC_GPIO13, HS2_CMD, SD_CMD, EMAC_RXD3           GPIO2 ADC2 CH2 TOUCH2 BTC GPIO12 HSPIWP HS2 DATAO	NC	18	-	See note <sup>2</sup>
NC         21         -         See note <sup>2</sup> NC         22         -         See note <sup>2</sup> IO15         23         I/O         GPIO15, ADC2_CH3, TOUCH3, MTDO, HSPICSO, RTC_GPIO13, HS2_CMD, SD_CMD, EMAC_RXD3           GPIO2 ADC2 CH2 TOUCH2 RTC GPIO12 HSPIWP HS2 DATAO	NC	19	-	See note <sup>2</sup>
NC 22 - See note <sup>2</sup> IO15 23 I/O GPIO15, ADC2_CH3, TOUCH3, MTDO, HSPICSO, RTC_GPIO13, HS2_CMD, SD_CMD, EMAC_RXD3  GPIO2_ADC2_CH2_TOUCH2_RTC_GPIO12_HSPIWP_HS2_DATA0	NC	20	-	See note <sup>2</sup>
IO15  23  I/O  GPIO15, ADC2_CH3, TOUCH3, MTDO, HSPICSO, RTC_GPIO13, HS2_CMD, SD_CMD, EMAC_RXD3  GPIO2_ADC2_CH2_TOUCH2_RTC_GPIO12_HSPIWP_HS2_DATA0	NC	21	-	See note <sup>2</sup>
HS2_CMD, SD_CMD, EMAC_RXD3  GPIO2_ADC2_CH2_TOUCH2_RTC_GPIO12_HSPIWP_HS2_DATA0	NC	22	-	See note <sup>2</sup>
HS2_CMD, SD_CMD, EMAC_RXD3  GPIO2_ADC2_CH2_TOLICH2_RTC_GPIO12_HSPIWP_HS2_DATA0	1015	00	1/0	GPIO15, ADC2_CH3, TOUCH3, MTDO, HSPICSO, RTC_GPIO13,
GPIO2, ADC2_CH2, TOUCH2, RTC_GPIO12, HSPIWP, HS2_DATA0,	1015	23	1/0	HS2_CMD, SD_CMD, EMAC_RXD3
	100	0.4	1/0	GPIO2, ADC2_CH2, TOUCH2, RTC_GPIO12, HSPIWP, HS2_DATA0,
102 24 1/O SD_DATA0	102	24	1/0	SD_DATA0
GPIO0, ADC2_CH1, TOUCH1, RTC_GPIO11, CLK_OUT1,	100	0.5	1/0	GPIO0, ADC2_CH1, TOUCH1, RTC_GPIO11, CLK_OUT1,
100 25 1/O EMAC_TX_CLK	100	25	1/0	EMAC_TX_CLK
GPIO4, ADC2_CH0, TOUCH0, RTC_GPIO10, HSPIHD, HS2_DATA1,	104	00	1/0	GPIO4, ADC2_CH0, TOUCH0, RTC_GPIO10, HSPIHD, HS2_DATA1,
104 26 1/O SD_DATA1, EMAC_TX_ER	IU4	20	1/0	SD_DATA1, EMAC_TX_ER
IO16 <sup>3</sup> 27 I/O GPIO16, HS1_DATA4, U2RXD, EMAC_CLK_OUT	IO16 <sup>3</sup>	27	I/O	GPIO16, HS1_DATA4, U2RXD, EMAC_CLK_OUT
IO17 28 I/O GPIO17, HS1_DATA5, U2TXD, EMAC_CLK_OUT_180	IO17	28	I/O	GPIO17, HS1_DATA5, U2TXD, EMAC_CLK_OUT_180
IO5 29 I/O GPIO5, VSPICSO, HS1_DATA6, EMAC_RX_CLK	IO5	29	I/O	GPIO5, VSPICSO, HS1_DATA6, EMAC_RX_CLK
IO18 30 I/O GPIO18, VSPICLK, HS1_DATA7	IO18	30	I/O	GPIO18, VSPICLK, HS1_DATA7

Name No. Type<sup>1</sup> **Function** GPIO19, VSPIQ, U0CTS, EMAC\_TXD0 IO19 I/O 31 NC 32 1021 33 I/O GPIO21, VSPIHD, EMAC TX EN RXD0 34 I/O GPIO3, U0RXD, CLK\_OUT2 TXD0 35 1/0 GPIO1, U0TXD, CLK OUT3, EMAC RXD2 1022 36 1/0 GPIO22, VSPIWP, UORTS, EMAC\_TXD1 1023 37 I/O GPIO23, VSPID, HS1 STROBE 38 Ρ **GND** Ground

Table 3 - cont'd from previous page

# 3.3 Strapping Pins

#### Note:

The content below is excerpted from Section Strapping Pins in <u>ESP32 Series Datasheet</u>. For the strapping pin mapping between the chip and modules, please refer to Chapter 5 <u>Module Schematics</u>.

ESP32 has five strapping pins:

- MTDI
- GPI00
- GPIO2
- MTDO
- GPI05

Software can read the values of these five bits from register "GPIO\_STRAPPING".

During the chip's system reset release (power-on-reset, RTC watchdog reset and brownout reset), the latches of the strapping pins sample the voltage level as strapping bits of "0" or "1", and hold these bits until the chip is powered down or shut down. The strapping bits configure the device's boot mode, the operating voltage of VDD\_SDIO and other initial system settings.

Each strapping pin is connected to its internal pull-up/pull-down during the chip reset. Consequently, if a strapping pin is unconnected or the connected external circuit is high-impedance, the internal weak pull-up/pull-down will determine the default input level of the strapping pins.

To change the strapping bit values, users can apply the external pull-down/pull-up resistances, or use the host MCU's GPIOs to control the voltage level of these pins when powering on ESP32.

After reset release, the strapping pins work as normal-function pins.

Refer to Table 4 for a detailed boot-mode configuration by strapping pins.

<sup>&</sup>lt;sup>1</sup> P: power supply; I: input; O: output.

<sup>&</sup>lt;sup>2</sup> Pins GPIO6 to GPIO11 on the ESP32-D0WD-V3/ESP32-D0WDR2-V3 chip are connected to the SPI flash integrated on the module and are not led out.

<sup>&</sup>lt;sup>3</sup> In module variants that have embedded QSPI PSRAM, i.e., that embed ESP32-D0WDR2-V3, IO16 is connected to the embedded PSRAM and can not be used for other functions.

		Voltage of Inte	ernal LDO (VDD	_SDIO)		
Pin	Default	3.3	3 V	1.8 V		
MTDI	Pull-down	(	)	1		
	Booting Mode					
Pin Default SPI Boot Download Boot					ad Boot	
GPI00	Pull-up	-	1	0		
GPIO2	Pull-down	Don't-care		0		
Enabling/Disabling Debugging Log Print over U0TXD During Booting						
Pin	Default	UOTXD	Active	U0TXD Silent		
MTDO	Pull-up	-	1	0		
	Timing of SDIO Slave					
		FE Sampling	FE Sampling	RE Sampling	RE Sampling	
Pin	Default	FE Output	RE Output	FE Output	RE Output	
MTDO	Pull-up	0	0	1	1	
GPIO5	Pull-up	0	1	0	1	

**Table 4: Strapping Pins** 

The illustration below shows the setup and hold times for the strapping pins before and after the CHIP\_PU signal goes high. Details about the parameters are listed in Table 5.

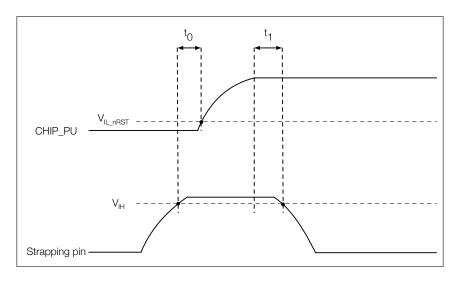


Figure 4: Setup and Hold Times for the Strapping Pins

Table 5: Parameter Descriptions of Setup and Hold Times for the Strapping Pins

Parameters	Description	Min.	Unit
$t_0$	Setup time before CHIP_PU goes from low to high	0	ms
$t_1$	Hold time after CHIP_PU goes high	1	ms

<sup>\*</sup> FE: falling-edge, RE: rising-edge

<sup>\*</sup> Firmware can configure register bits to change the settings of "Voltage of Internal LDO (VDD\_SDIO)" and "Timing of SDIO Slave", after booting.

<sup>\*</sup> The module integrates a 3.3 V SPI flash, so the pin MTDI cannot be set to 1 when the module is powered up.

# **Electrical Characteristics**

#### 4.1 **Absolute Maximum Ratings**

Stresses above those listed in Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

**Table 6: Absolute Maximum Ratings** 

Symbol	Parameter	Min	Max	Unit
VDD33	Power supply voltage	-0.3	3.6	V
$T_{STORE}$	Storage temperature	-40	105	°C

<sup>\*</sup> Please **Appendix** Ю MUX of ESP32 Series Datasheet for IO's power domain.

# **Recommended Operating Conditions**

**Table 7: Recommended Operating Conditions** 

Symbol	Parameter			Тур	Max	Unit
VDD33	Power supply voltage		3.0	3.3	3.6	V
$I_{VDD}$	Current delivered by external power supply				_	Α
Т	Operating ambient temperature	85 °C version	-40	_	85	°C
		105 °C version	<del>-4</del> 0		105	

# 4.3 DC Characteristics (3.3 V, 25 °C)

Table 8: DC Characteristics (3.3 V, 25 °C)

Symbol	Parameter	Min	Тур	Max	Unit
$C_{IN}$	Pin capacitance	_	2	_	рF
$V_{IH}$	High-level input voltage	$0.75 \times VDD^1$	_	VDD <sup>1</sup> + 0.3	V
$V_{IL}$	Low-level input voltage	-0.3		$0.25 \times VDD^1$	V
$ I_{IH} $	High-level input current	_	_	50	nA
$ I_{IL} $	Low-level input current	_		50	nA
$V_{OH}$	High-level output voltage	$0.8 \times VDD^1$	_	_	V
$V_{OL}$	Low-level output voltage	_	_	$0.1 \times VDD^1$	V

**Symbol** Unit **Parameter** Тур Max Min VDD3P3 CPU High-level source current 40 mΑ power domain 1, 2  $(VDD^1 = 3.3 V,$ VDD3P3 RTC  $V_{OH} >= 2.64 \text{ V},$ 40 mA  $|_{OH}$ power domain 1, 2 output drive strength set VDD\_SDIO power to the maximum) 20 mΑ domain 1,3 Low-level sink current  $(VDD^1 = 3.3 \text{ V}, V_{OL} = 0.495 \text{ V},$ 28 mA  $I_{OL}$ output drive strength set to the maximum) Resistance of internal pull-up resistor 45  $k\Omega$  $R_{PU}$  $R_{PD}$ Resistance of internal pull-down resistor 45  $k\Omega$ Low-level input voltage of CHIP PU V  $V_{IL\_nRST}$ 0.6 to shut down the chip

Table 8 - cont'd from previous page

# 4.4 Current Consumption Characteristics

Owing to the use of advanced power-management technologies, the module can switch between different power modes. For details on different power modes, please refer to Section RTC and Low-Power Management in ESP32 Series Datasheet.

Work mode	Desc	cription	Average (mA)	Peak (mA)
Active (RF working)	TX RX	802.11b, 20 MHz, 1 Mbps, @19.5 dBm	239	379
		802.11g, 20 MHz, 54 Mbps, @15 dBm	190	276
		802.11n, 20 MHz, MCS7, @13 dBm	183	258
		802.11n, 40 MHz, MCS7, @13 dBm	165	211
		802.11b/g/n, 20 MHz	112	112
		802.11n, 40 MHz	118	118

<sup>&</sup>lt;sup>1</sup> The current consumption measurements are taken with a 3.3 V supply at 25 °C of ambient temperature at the RF port. All transmitters' measurements are based on a 50% duty cycle.

<sup>&</sup>lt;sup>1</sup> Please see Appendix IO MUX of <u>ESP32 Series Datasheet</u> for IO's power domain. VDD is the I/O voltage for a particular power domain of pins.

<sup>&</sup>lt;sup>2</sup> For VDD3P3\_CPU and VDD3P3\_RTC power domain, per-pin current sourced in the same domain is gradually reduced from around 40 mA to around 29 mA,  $V_{OH}>=2.64$  V, as the number of current-source pins increases.

<sup>&</sup>lt;sup>3</sup> Pins occupied by flash and/or PSRAM in the VDD\_SDIO power domain were excluded from the test.

<sup>&</sup>lt;sup>2</sup> The current consumption figures for in RX mode are for cases when the peripherals are disabled and the CPU idle.

#### Wi-Fi RF Characteristics 4.5

#### 4.5.1 Wi-Fi RF Standards

Table 10: Wi-Fi RF Standards

Name		Description		
Center frequency range of operating channel		2412 ~ 2484 MHz		
Wi-Fi wireless standard		IEEE 802.11b/g/n		
		11b: 1, 2, 5.5, 11 Mbps		
Data rate	20 MHz	11g: 6, 9, 12, 18, 24, 36, 48, 54 Mbps		
Data Tale		11n: MCS0-7, 72.2 Mbps (Max)		
	40 MHz	11n: MCS0-7, 150 Mbps (Max)		
Antenna type		PCB antenna, external antenna <sup>2</sup>		

<sup>&</sup>lt;sup>1</sup> Device should operate in the center frequency range allocated by regional regulatory authorities. Target center frequency range is configurable by software.

### 4.5.2 Transmitter Characteristics

Target TX power is configurable based on device or certification requirements. The default characteristics are provided in Table 11.

**Table 11: TX Power Characteristics** 

Rate	Typ (dBm)
11b, 1 Mbps	19.5
11b, 11 Mbps	19.5
11g, 6 Mbps	18
11g, 54 Mbps	14
11n, HT20, MCS0	18
11n, HT20, MCS7	13
11n, HT40, MCS0	18
11n, HT40, MCS7	13

### 4.5.3 Receiver Characteristics

Table 12: RX Sensitivity Characteristics

Rate	Typ (dBm)
1 Mbps	-97
2 Mbps	-94
5.5 Mbps	-92
11 Mbps	-88

 $<sup>^2</sup>$  For the modules that use external antennas, the output impedance is 50  $\Omega$ . For other modules without external antennas, the output impedance is irrelevant.

Table 12 - cont'd from previous page

Rate	Typ (dBm)
6 Mbps	-93
9 Mbps	-91
12 Mbps	-89
18 Mbps	-87
24 Mbps	-84
36 Mbps	-80
48 Mbps	<b>–</b> 77
54 Mbps	-75
11n, HT20, MCS0	-92
11n, HT20, MCS1	-88
11n, HT20, MCS2	-86
11n, HT20, MCS3	-83
11n, HT20, MCS4	-80
11n, HT20, MCS5	-76
11n, HT20, MCS6	-74
11n, HT20, MCS7	<del>-</del> 72
11n, HT40, MCS0	-89
11n, HT40, MCS1	-85
11n, HT40, MCS2	-83
11n, HT40, MCS3	-80
11n, HT40, MCS4	-76
11n, HT40, MCS5	-72
11n, HT40, MCS6	<b>–</b> 71
11n, HT40, MCS7	-69

Table 13: RX Maximum Input Level

Rate	Typ (dBm)
11b, 1 Mbps	5
11b, 11 Mbps	5
11g, 6 Mbps	0
11g, 54 Mbps	-8
11n, HT20, MCS0	0
11n, HT20, MCS7	-8
11n, HT40, MCS0	0
11n, HT40, MCS7	-8

Table 14: Adjacent Channel Rejection

Rate	Typ (dB)
11b, 11 Mbps	35
11g, 6 Mbps	27

Table 14 - cont'd from previous page

Rate	Typ (dB)
11g, 54 Mbps	13
11n, HT20, MCS0	27
11n, HT20, MCS7	12
11n, HT40, MCS0	16
11n, HT40, MCS7	7

# 4.6 Bluetooth Radio

# 4.6.1 Receiver - Basic Data Rate

Table 15: Receiver Characteristics - Basic Data Rate

Parameter	Conditions	Min	Тур	Max	Unit
Sensitivity @0.1% BER	_	-90	-89	-88	dBm
Maximum received signal @0.1% BER	_	0		_	dBm
Co-channel C/I	_	_	+7	_	dB
	F = F0 + 1 MHz	_		-6	dB
	F = F0 – 1 MHz	_		-6	dB
Adjacent channel colectivity C/I	F = F0 + 2 MHz	_		-25	dB
Adjacent channel selectivity C/I	F = F0 – 2 MHz	_		-33	dB
	F = F0 + 3 MHz	_		-25	dB
	F = F0 - 3  MHz	_		-45	dB
	30 MHz ~ 2000 MHz	-10	_	_	dBm
Out-of-band blocking performance	2000 MHz ~ 2400 MHz	-27		_	dBm
	2500 MHz ~ 3000 MHz	-27		_	dBm
	3000 MHz ~ 12.5 GHz	-10	_	_	dBm
Intermodulation	_	-36	_	_	dBm

# 4.6.2 Transmitter - Basic Data Rate

Table 16: Transmitter Characteristics - Basic Data Rate

Parameter	Conditions	Min	Тур	Max	Unit
RF transmit power*	_	_	0	_	dBm
Gain control step	_	_	3	_	dB
RF power control range	_	-12		+9	dBm
+20 dB bandwidth	_	_	0.9	_	MHz
	$F = F0 \pm 2 MHz$	_	-55	_	dBm
Adjacent channel transmit power	$F = F0 \pm 3 \text{ MHz}$		-55	_	dBm
	$F = F0 \pm > 3 MHz$		-59	_	dBm
$\Delta f1_{ ext{avg}}$				155	kHz
$\Delta f2_{ ext{max}}$	_	127	_	_	kHz

Table 16 - cont'd from previous page

Parameter	Conditions	Min	Тур	Max	Unit
$\Delta f 2_{\text{avg}}/\Delta f 1_{\text{avg}}$	_	_	0.92	_	_
ICFT	_	_	-7	_	kHz
Drift rate	_	_	0.7	_	kHz/50 $\mu$ s
Drift (DH1)	_	_	6	_	kHz
Drift (DH5)	_		6	_	kHz

<sup>\*</sup> There are a total of eight power levels from 0 to 7, and the transmit power ranges from –12 dBm to 9 dBm. When the power level rises by 1, the transmit power increases by 3 dB. Power level 4 is used by default and the corresponding transmit power is 0 dBm.

### 4.6.3 Receiver - Enhanced Data Rate

Table 17: Receiver Characteristics - Enhanced Data Rate

Parameter	Conditions	Min	Тур	Max	Unit	
$\pi$ /4 DQPSK						
Sensitivity @0.01% BER	_	-90	-89	-88	dBm	
Maximum received signal @0.01% BER	_	_	0	_	dBm	
Co-channel C/I	_	_	11	_	dB	
	F = F0 + 1 MHz		-7	_	dB	
	F = F0 - 1 MHz		-7	_	dB	
Adjacent channel selectivity C/I	F = F0 + 2 MHz		-25	_	dB	
	F = F0 - 2 MHz	_	-35	_	dB	
	F = F0 + 3 MHz		-25	_	dB	
	F = F0 - 3 MHz	_	-45	_	dB	
8DPSK						
Sensitivity @0.01% BER	_	-84	-83	-82	dBm	
Maximum received signal @0.01% BER	_	_	-5	_	dBm	
C/I c-channel	_	_	18	_	dB	
Adjacent channel selectivity C/I	F = F0 + 1 MHz	_	2	_	dB	
	F = F0 - 1 MHz	_	2	_	dB	
	F = F0 + 2 MHz	_	-25	_	dB	
	F = F0 - 2 MHz	_	-25	_	dB	
	F = F0 + 3 MHz	_	-25	_	dB	
	F = F0 - 3  MHz		-38		dB	

### 4.6.4 Transmitter - Enhanced Data Rate

Table 18: Transmitter Characteristics - Enhanced Data Rate

Parameter	Conditions	Min	Тур	Max	Unit
RF transmit power (see note under Table 16)	_	_	0	_	dBm
Gain control step	_	_	3	_	dB
RF power control range	_	-12	_	+9	dBm

Parameter	Conditions	Min	Тур	Max	Unit
$\pi/4$ DQPSK max w0	_	_	-0.72	_	kHz
$\pi/4$ DQPSK max wi	_	_	-6	_	kHz
$\pi/4$ DQPSK max lwi + w0l	_	_	-7.42	_	kHz
8DPSK max w0	_	_	0.7	_	kHz
8DPSK max wi	_	_	-9.6	_	kHz
8DPSK max lwi + w0l	_	_	-10	_	kHz
	RMS DEVM		4.28		%
$\pi/4$ DQPSK modulation accuracy	99% DEVM	_	100	_	%
	Peak DEVM	_	13.3	_	%
	RMS DEVM	_	5.8	_	%
8 DPSK modulation accuracy	99% DEVM	_	100	_	%
	Peak DEVM	_	14	_	%
In-band spurious emissions	$F = F0 \pm 1 MHz$	_	-46	_	dBm
	$F = F0 \pm 2 MHz$	_	-44	_	dBm
	$F = F0 \pm 3 \text{ MHz}$	_	-49	_	dBm
	F = F0 + /- > 3 MHz	_		-53	dBm
EDR differential phase coding	_	_	100	_	%

# **Bluetooth LE Radio**

# 4.7.1 Receiver

Table 19: Receiver Characteristics - Bluetooth LE

Parameter	Conditions	Min	Тур	Max	Unit
Sensitivity @30.8% PER	_	-94	-93	-92	dBm
Maximum received signal @30.8% PER	_	0	_		dBm
Co-channel C/I	_	_	+10	_	dB
Adjacent channel selectivity C/I	F = F0 + 1 MHz	_	-5	_	dB
	F = F0 – 1 MHz	_	-5	_	dB
	F = F0 + 2 MHz	_	-25	_	dB
	F = F0 - 2 MHz	_	-35		dB
	F = F0 + 3 MHz	_	-25	-	dB
	F = F0 - 3 MHz	_	-45		dB
	30 MHz ~ 2000 MHz	-10	_	_	dBm
Out-of-band blocking performance	2000 MHz ~ 2400 MHz	-27		_	dBm
	2500 MHz ~ 3000 MHz	-27	_		dBm
	3000 MHz ~ 12.5 GHz	-10	_		dBm
Intermodulation	_	-36		_	dBm

# 4.7.2 Transmitter

Table 20: Transmitter Characteristics - Bluetooth LE

Parameter	Conditions	Min	Тур	Max	Unit
RF transmit power (see note under Table 16)	_	_	0	_	dBm
Gain control step	_		3	_	dB
RF power control range	_	-12	_	+9	dBm
	$F = F0 \pm 2 MHz$	_	-55	_	dBm
Adjacent channel transmit power	$F = F0 \pm 3 \text{ MHz}$		-57	_	dBm
	$F = F0 \pm > 3 MHz$	_	-59	_	dBm
$\Delta f1_{ ext{avg}}$	_	_	_	265	kHz
$\Delta~f2_{\sf max}$	_	210	_	_	kHz
$\Delta f 2_{\text{avg}}/\Delta f 1_{\text{avg}}$	_		+0.92	_	_
ICFT	_	_	-10	_	kHz
Drift rate	_	_	0.7	_	kHz/50 μs
Drift	_	_	2	_	kHz

S

# 5 Module Schematics

This is the reference design of the module.

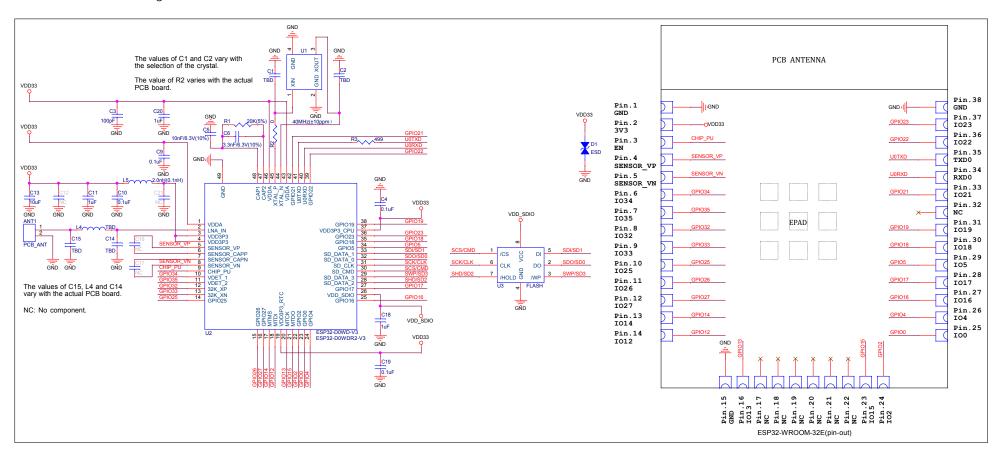


Figure 5: ESP32-WROOM-32E Schematics

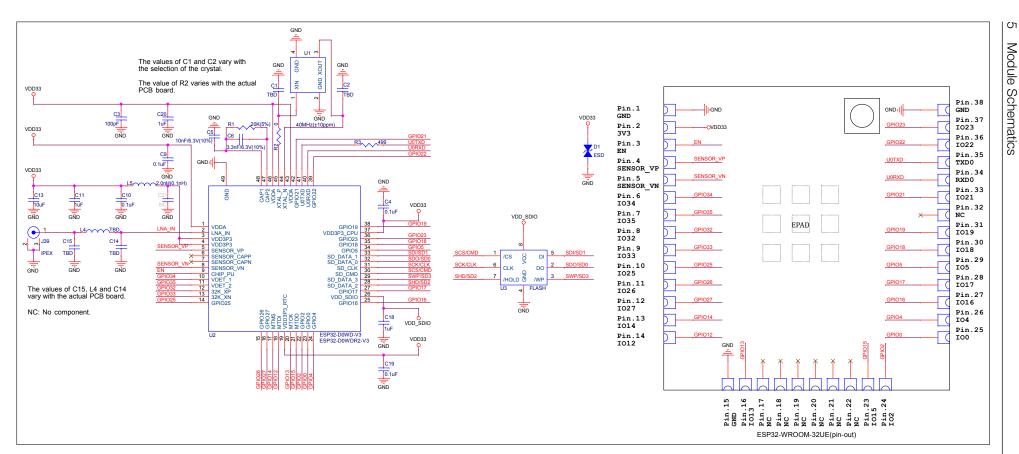


Figure 6: ESP32-WROOM-32UE Schematics

# 6 Peripheral Schematics

This is the typical application circuit of the module connected with peripheral components (for example, power supply, antenna, reset button, JTAG interface, and UART interface).

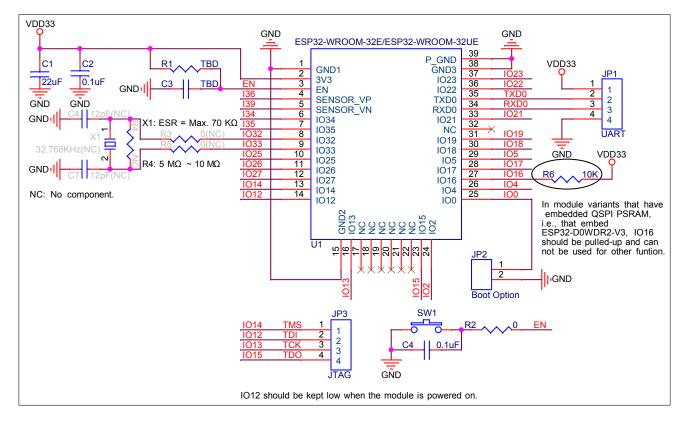


Figure 7: Peripheral Schematics

- Soldering EPAD Pin 39 to the ground of the base board is not a must, however, it can optimize thermal performance. If you choose to solder it, please apply the correct amount of soldering paste.
- To ensure that the power supply to the ESP32 chip is stable during power-up, it is advised to add an RC delay circuit at the EN pin. The recommended setting for the RC delay circuit is usually R = 10 k $\Omega$  and C = 1  $\mu$ F. However, specific parameters should be adjusted based on the power-up timing of the module and the power-up and reset sequence timing of the chip. For ESP32's power-up and reset sequence timing diagram, please refer to Section *Power Scheme* in *ESP32 Series Datasheet*.

# **Physical Dimensions and PCB Land Pattern**

# **Physical Dimensions**

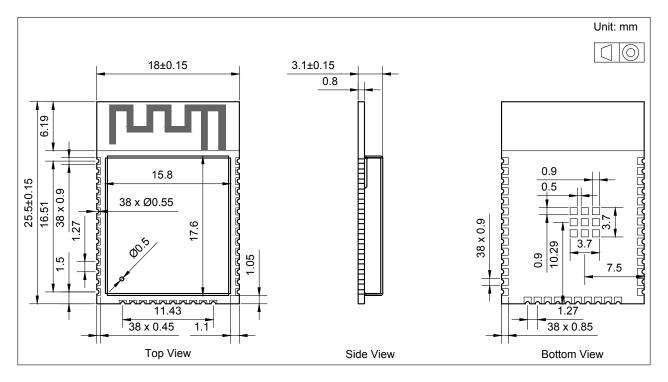


Figure 8: ESP32-WROOM-32E Physical Dimensions

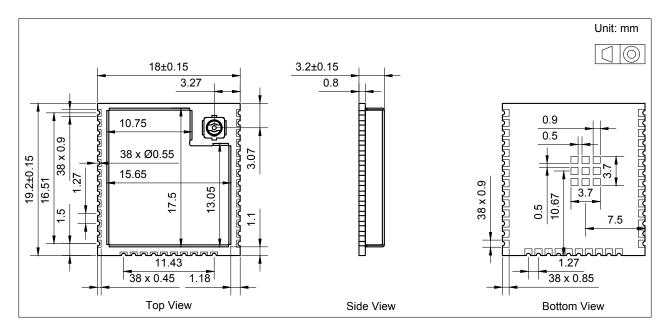


Figure 9: ESP32-WROOM-32UE Physical Dimensions

#### Note:

For information about tape, reel, and product marking, please refer to Espressif Module Package Information.

#### 7

# 7.2 Recommended PCB Land Pattern

This section provides the following resources for your reference:

- Figures for recommended PCB land patterns with all the dimensions needed for PCB design. See Figure 10 ESP32-WROOM-32E Recommended PCB Land Pattern and Figure 11 ESP32-WROOM-32UE Recommended PCB Land Pattern.
- Source files of recommended PCB land patterns to measure dimensions not covered in Figure 10 and Figure 11. You can view the source files for <u>ESP32-WROOM-32E</u> and <u>ESP32-WROOM-32UE</u> with Autodesk Viewer.
- 3D models of <u>ESP32-WROOM-32E</u> and <u>ESP32-WROOM-32UE</u>. Please make sure that you download the 3D model file in .STEP format (beware that some browsers might add .txt).

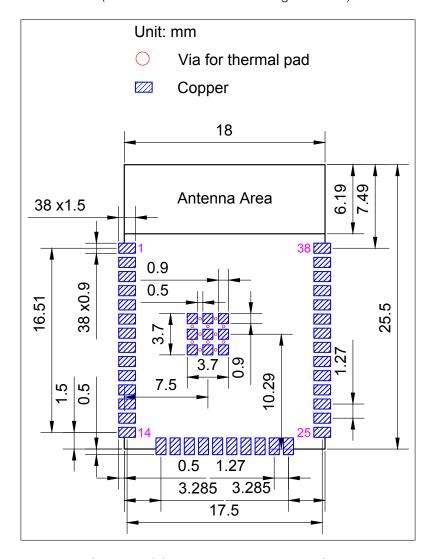


Figure 10: ESP32-WROOM-32E Recommended PCB Land Pattern



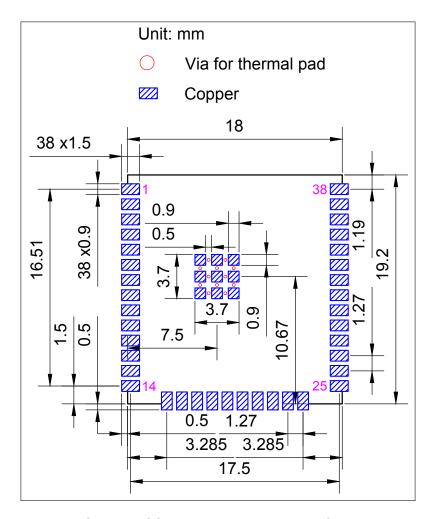


Figure 11: ESP32-WROOM-32UE Recommended PCB Land Pattern

# 7.3 Dimensions of External Antenna Connector

ESP32-WROOM-32UE uses the first generation external antenna connector as shown in Figure 12. This connector is compatible with the following connectors:

- U.FL Series connector from Hirose
- MHF I connector from I-PEX
- AMC connector from Amphenol

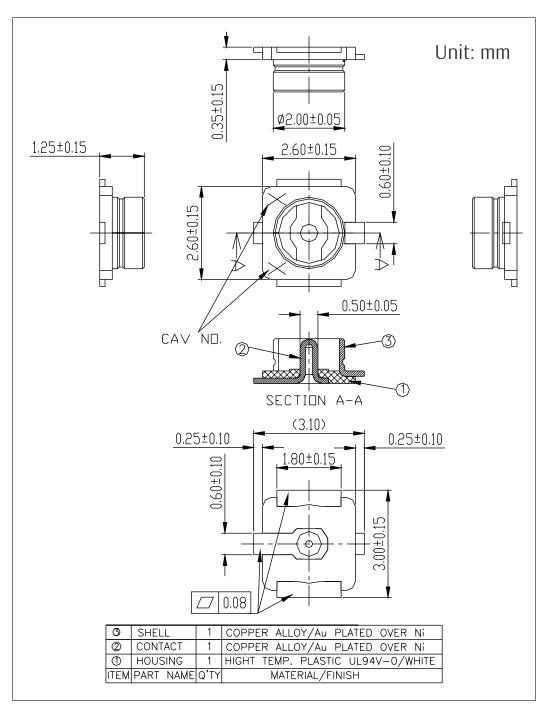


Figure 12: Dimensions of External Antenna Connector

# 8 Product Handling

# 8.1 Storage Conditions

The products sealed in moisture barrier bags (MBB) should be stored in a non-condensing atmospheric environment of < 40 °C and 90%RH. The module is rated at the moisture sensitivity level (MSL) of 3.

After unpacking, the module must be soldered within 168 hours with the factory conditions  $25 \pm 5$  °C and 60 %RH. If the above conditions are not met, the module needs to be baked.

# 8.2 Electrostatic Discharge (ESD)

Human body model (HBM): ±2000 V
 Charged device model (CDM): ±500 V

• Charged-device model (CDM): ±500 V

# 8.3 Reflow Profile

Solder the module in a single reflow.

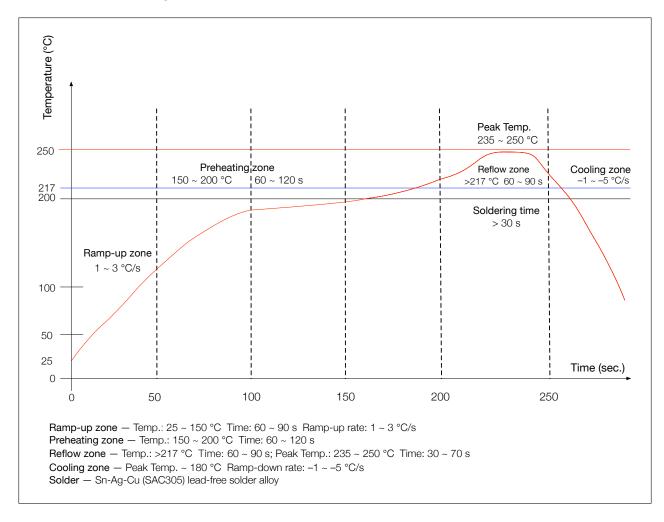


Figure 13: Reflow Profile

#### **Ultrasonic Vibration** 8.4

Avoid exposing Espressif modules to vibration from ultrasonic equipment, such as ultrasonic welders or ultrasonic cleaners. This vibration may induce resonance in the in-module crystal and lead to its malfunction or even failure. As a consequence, the module may stop working or its performance may deteriorate.

# 9 Related Documentation and Resources

## **Related Documentation**

- ESP32 Series Datasheet Specifications of the ESP32 hardware.
- ESP32 Technical Reference Manual Detailed information on how to use the ESP32 memory and peripherals.
- ESP32 Hardware Design Guidelines Guidelines on how to integrate the ESP32 into your hardware product.
- ESP32 ECO and Workarounds for Bugs Correction of ESP32 design errors.
- Certificates

https://espressif.com/en/support/documents/certificates

• ESP32 Product/Process Change Notifications (PCN)

https://espressif.com/en/support/documents/pcns

• ESP32 Advisories - Information on security, bugs, compatibility, component reliability.

https://espressif.com/en/support/documents/advisories

• Documentation Updates and Update Notification Subscription

https://espressif.com/en/support/download/documents

# **Developer Zone**

- ESP-IDF Programming Guide for ESP32 Extensive documentation for the ESP-IDF development framework.
- ESP-IDF and other development frameworks on GitHub.

https://github.com/espressif

• ESP32 BBS Forum – Engineer-to-Engineer (E2E) Community for Espressif products where you can post questions, share knowledge, explore ideas, and help solve problems with fellow engineers.

https://esp32.com/

• The ESP Journal - Best Practices, Articles, and Notes from Espressif folks.

https://blog.espressif.com/

• See the tabs SDKs and Demos, Apps, Tools, AT Firmware.

https://espressif.com/en/support/download/sdks-demos

## **Products**

• ESP32 Series SoCs - Browse through all ESP32 SoCs.

https://espressif.com/en/products/socs?id=ESP32

• ESP32 Series Modules – Browse through all ESP32-based modules.

https://espressif.com/en/products/modules?id=ESP32

ESP32 Series DevKits – Browse through all ESP32-based devkits.

https://espressif.com/en/products/devkits?id=ESP32

• ESP Product Selector – Find an Espressif hardware product suitable for your needs by comparing or applying filters. https://products.espressif.com/#/product-selector?language=en

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# **Revision History**

Date	Version	Release notes				
		Major updates:				
2023-01-18		<ul> <li>Removed contents about hall sensor according to PCN20221202</li> </ul>				
	v1.6	Other updates:				
		Added source files of PCB land patterns and 3D models of the modules in				
		Section 7.2: Recommended PCB Land Pattern				
		Added module variants embedded with ESP32-D0WDR2-V3 chip				
		Added Table 1: ESP32-WROOM-32E Series Comparison and Table 2: ESP32-				
2022-07-20	v1.5	WROOM-32UE Series Comparison				
		Added Figure 4 and Table 5 in Section 3.3: Strapping Pins				
		Updated Section 8: Product Handling				
2022-02-22	v1.4	Added a link to RF certificates in Section 1.1				
2022-02-22	V1.4	Fixed a pin name typo in Figure 7				
		Added a 105 °C module variant				
		Updated Table 6: Absolute Maximum Ratings				
	v1.3	Updated Table 7: Recommended Operating Conditions				
2021-11-08		Replaced Espressif Product Ordering Information with ESP Product Selector				
2021-11-00		Updated the description of TWAI in Section 1.1: Features				
		Added a note below Figure 9: ESP32-WROOM-32UE Physical Dimensions				
		Upgraded figure formatting				
		Upgraded document formatting				
		Updated Figure 10: ESP32-WROOM-32E Recommended PCB Land Pattern,				
	v1.2	Figure 11: ESP32-WROOM-32UE Recommended PCB Land Pattern, Figure 8:				
2021-02-09		ESP32-WROOM-32E Physical Dimensions, and Figure 9: ESP32-WROOM-32UE				
2021 02 00		Physical Dimensions.				
		Modified the note below Figure 13: Reflow Profile.				
		Updated the trade mark from TWAI™ to TWAI®.				
		Updated the table 9.				
2020-11-02	v1.1	Added a note to EPAD in Section 7.2 Recommended PCB Land Pattern.				
		Updated the note to RC circuit in Section 6 Peripheral Schematics.				
2020-05-29	v1.0	Official release.				
2020-05-18	v0.5	Preliminary release.				



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